

## 20V/6.5A N-Channel MOSFET

### Features

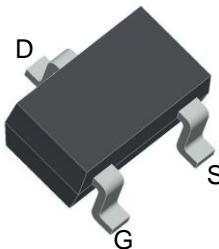
- High Power and current handing capability
- Lead free product is acquired
- Surface mount package

### Product Summary

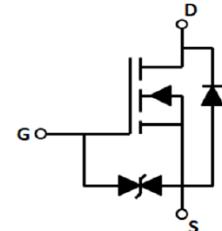
$V_{DS}$	$R_{DS(ON)} \text{ MAX}$	$I_D \text{ MAX}$
20V	22mΩ@4.5V	6.5A
	26mΩ@2.5V	

### Application

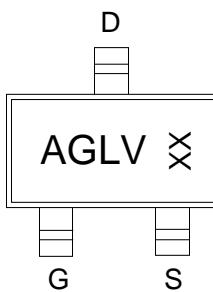
- Load Switch
- PWM Application
- Power



SOT-23-3L top view



Schematic diagram



Marking and pin assignment

AGLV : Device code  
XX : Code



Pb-Free



RoHS



Halogen-Free

### Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Rating	Unit
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### Common Ratings ( $T_C=25^\circ\text{C}$ Unless Otherwise Noted)

$V_{DS}$	Drain-Source Breakdown Voltage	20	V
$V_{GS}$	Gate-Source Voltage	$\pm 12$	V
$T_J$	Maximum Junction Temperature	150	°C
$T_{STG}$	Storage Temperature Range	-50 to 155	°C
$I_S$	Diode Continuous Forward Current	6.5	A

### Mounted on Large Heat Sink

$I_{DM}$	Pulse Drain Current Tested	$T_C=25^\circ\text{C}$	30	A
$I_D$	Continuous Drain Current @ $GS=10V$	$T_C=25^\circ\text{C}$	6.5	A
$P_D$	Maximum Power Dissipation	$T_C=25^\circ\text{C}$	1.4	W
$R_{\theta JA}$	Thermal Resistance Junction-to-Ambient @ Steady State		125	°C/W

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, ID=250μA	20	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	--	--	1	uA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V	--	--	±10	uA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , ID=250μA	0.4	0.7	1.1	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =4.5V, ID=6.5A	--	17	22	mΩ
		V <sub>GS</sub> =2.5V, ID=5.5A	--	20	26	mΩ
		V <sub>GS</sub> =1.8V, ID=5.0A	--	35	50	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHz	--	660	--	pF
C <sub>OSS</sub>	Output Capacitance		--	160	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	90	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =10V, ID=6.5A, V <sub>GS</sub> =4.5V	--	8	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	2.5	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	3	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =10V, ID=0.5A, V <sub>GS</sub> =4.5V, RG=10Ω	--	0.5	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	1	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	12	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	4	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>j</sub> =25°C, I <sub>s</sub> =6.5A,	--	--	1.2	V

## Typical Operating Characteristics

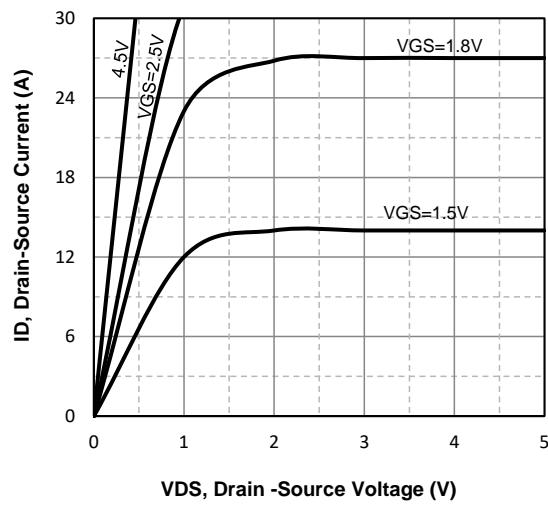


Fig1. Typical Output Characteristics

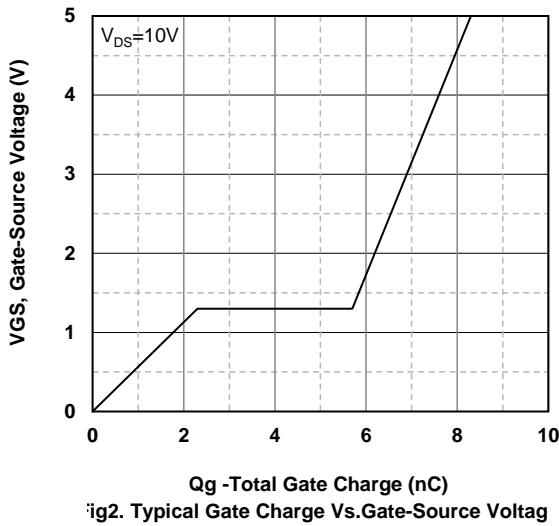


Fig2. Typical Gate Charge Vs. Gate-Source Voltage

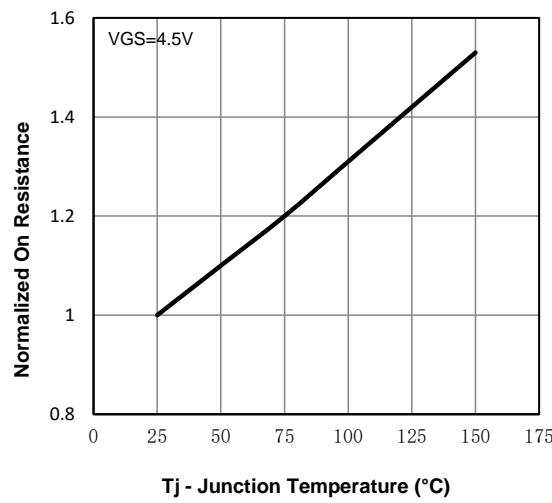


Fig3. Normalized On-Resistance Vs. Temperature

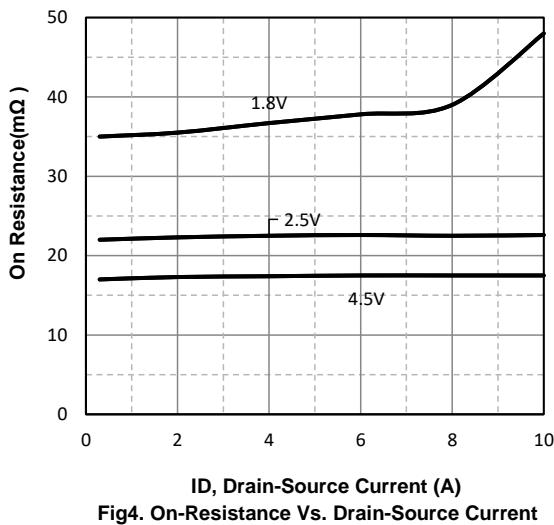


Fig4. On-Resistance Vs. Drain-Source Current

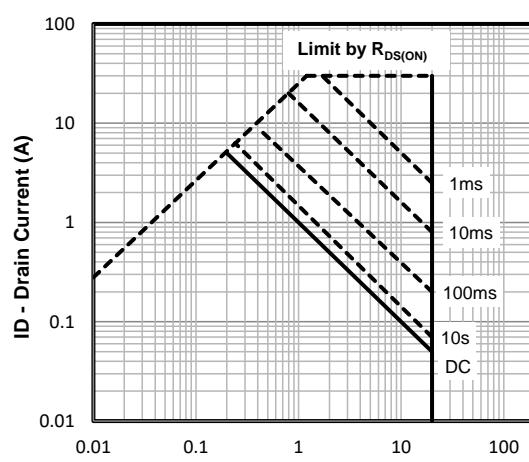


Fig5. Maximum Safe Operating Area

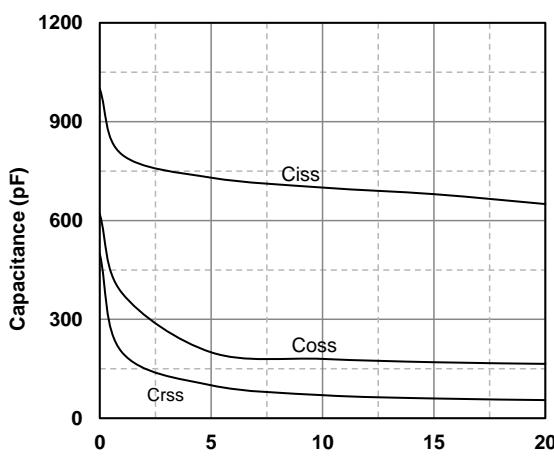
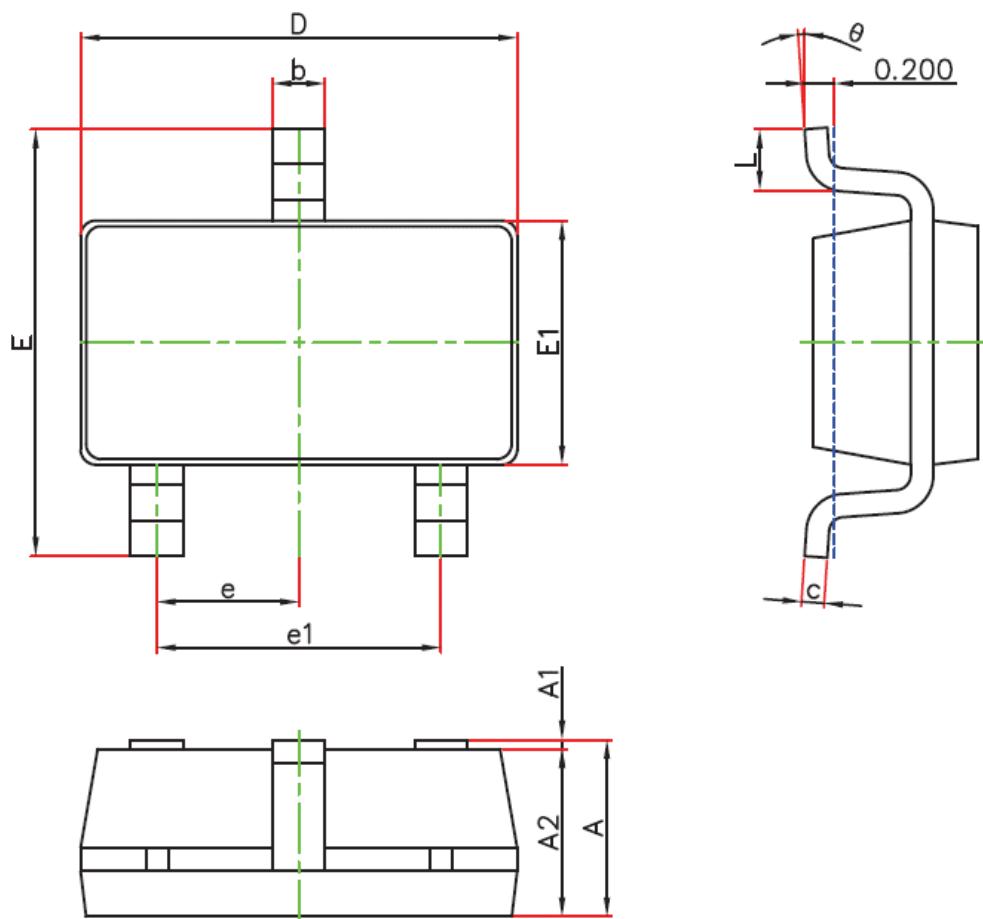


Fig6. Typical Capacitance Vs. Drain-Source Voltage

## SOT-23-3L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

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